

## ULTRA FAST RECTIFIERS

VOLTAGE RANGE: 50 -- 600 V  
CURRENT: 1.0 A

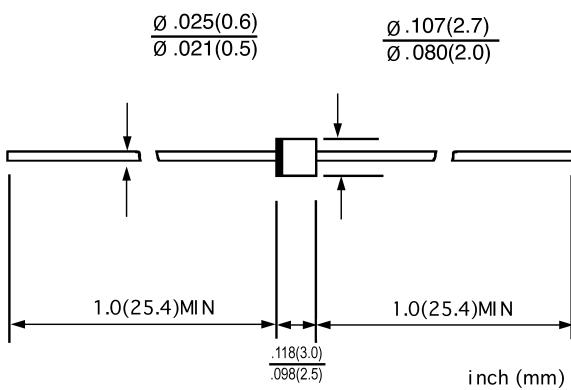
## FEATURES

- ◇ Low cost
- ◇ Glass passivated junction
- ◇ Ultra fast switching for high efficiency
- ◇ Low reverse leakage current
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ The plastic material carries U/L recognition 94V-0

## MECHANICAL DATA

- ◇ Case: JEDEC R-1, molded plastic
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.20 grams
- ◇ Mounting position: Any

R - 1



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

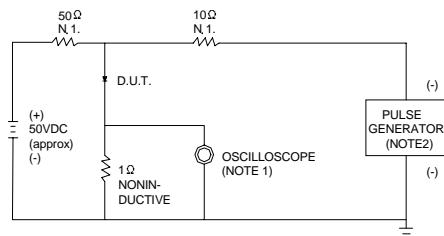
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		1E1G	1E2G	1E3G	1E4G	1E5G	1E6G	UNITS			
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	V			
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	V			
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	V			
Maximum average forward rectified current 9.5mm lead length, $\text{@ } T_A = 75^\circ\text{C}$	$I_{F(AV)}$	1.0						A			
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load $\text{@ } T_J = 125^\circ\text{C}$	$I_{FSM}$	30.0						A			
Maximum instantaneous forward voltage $\text{@ } 1.0\text{A}$	$V_F$	0.95		1.25	1.7			V			
Maximum reverse current $\text{@ } T_A = 25^\circ\text{C}$ at rated DC blocking voltage $\text{@ } T_A = 150^\circ\text{C}$	$I_R$	5.0 150.0						$\mu\text{A}$			
Maximum reverse recovery time (Note1)	$t_{rr}$	35						ns			
Typical junction capacitance (Note2)	$C_J$	17						pF			
Typical thermal resistance (Note3)	$R_{\theta JA}$	50						$^\circ\text{C/W}$			
Operating junction temperature range	$T_J$	- 55 ----- + 175						$^\circ\text{C}$			
Storage temperature range	$T_{STG}$	- 55 ----- + 175						$^\circ\text{C}$			

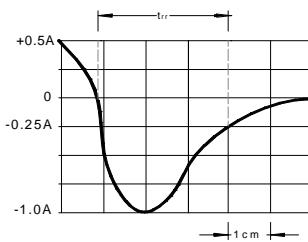
NOTE: 1. Measured with  $I_F=0.5\text{A}$ ,  $I_R=1\text{A}$ ,  $I_{rr}=0.25\text{A}$ .

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

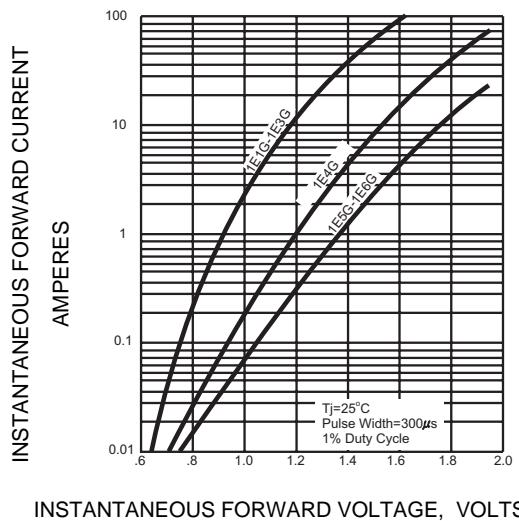
3. Thermal resistance junction to ambient

FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC

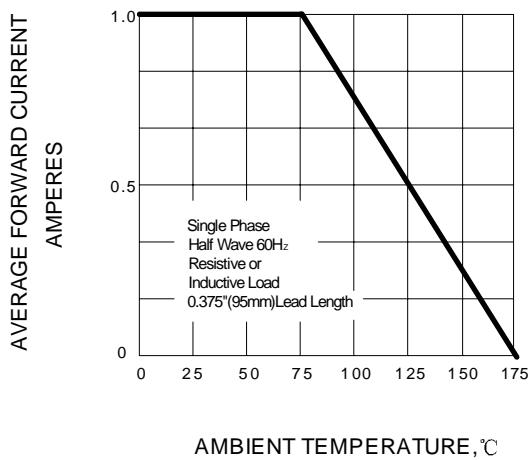
NOTES:  
1.RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1M $\Omega$ .22pF.  
2.RISE TIME = 10ns MAX.SOURCE IMPEDANCE=50  $\Omega$ .



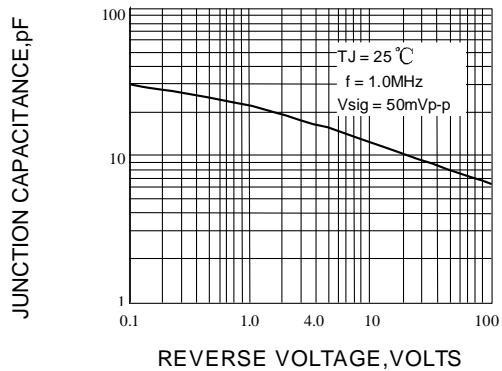
SET TIME BASE FOR 10 ns/cm

FIG.2 -- TYPICAL FORWARD CHARACTERISTIC

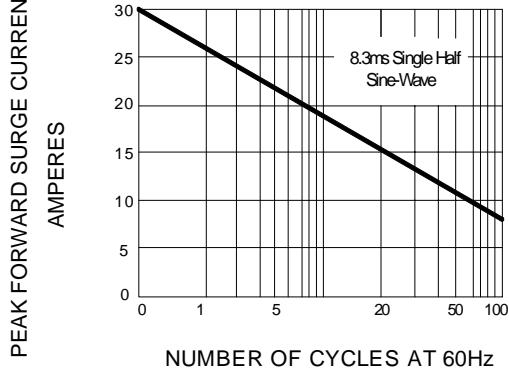
INSTANTANEOUS FORWARD VOLTAGE, VOLTS

FIG.3 -- FORWARD DERATING CURVE

AMBIENT TEMPERATURE, °C

FIG.4 -- TYPICAL JUNCTION CAPACITANCE

REVERSE VOLTAGE, VOLTS

FIG.5 -- PEAK FORWARD SURGE CURRENT

NUMBER OF CYCLES AT 60Hz